

DS90CF563/DS90CF564 LVDS 18-Bit Color Flat Panel Display (FPD) Link - 65 MHz

Check for Samples: DS90CF563, DS90CF564

FEATURES

- 20 to 65 MHz Shift Clk Support
- Up to 171 Mbytes/s Bandwidth
- Cable Size is Reduced to Save Cost
- 290 mV Swing LVDS Devices for Low EMI
- Low Power CMOS Design (< 550 mW typ)
- Power-down Mode Saves Power (< 0.25 mW)
- **PLL Requires No External Components**
- Low Profile 48-Lead TSSOP Package
- Falling Edge Data Strobe
- Compatible with TIA/EIA-644 LVDS Standard
- Single Pixel Per Clock XGA (1024 x 768)
- Supports VGA, SVGA, XGA and Higher
- 1.3 Gbps Throughput

DESCRIPTION

The DS90CF563 transmitter converts 21 bits of CMOS/TTL data into three LVDS (Low Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fourth LVDS link. Every cycle of the transmit clock 21 bits of input data are sampled and transmitted. The DS90CF564 receiver converts the LVDS data streams back into 21 bits of CMOS/TTL data. At a transmit clock frequency of 65 MHz, 18 bits of RGB data and 3 bits of LCD timing and control data (FPLINE, FPFRAME, DRDY) are transmitted at a rate of 455 Mbps per LVDS data channel. Using a 65 MHz clock, the data throughput is 171 Mbytes per second. These devices are offered with falling edge data strobes for convenient interface with a variety of graphics and LCD panel controllers.

This chipset is an ideal means to solve EMI and cable size problems associated with wide, high speed TTL interfaces.

Block Diagram

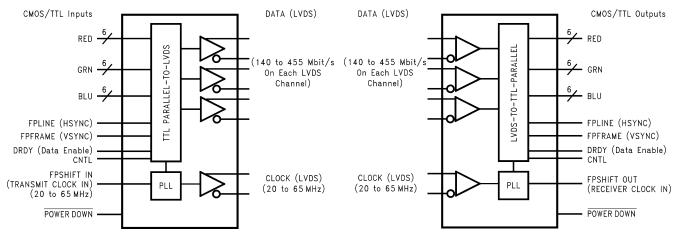


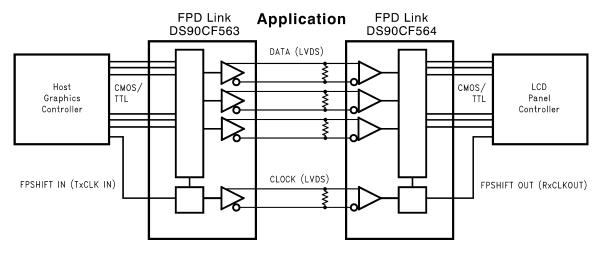
Figure 1. DS90CF563 DS90CF563MTD is no longer available.

Figure 2. DS90CF564 See Package Number DGG0048A

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Application



Absolute Maximum Ratings(1)(2)

Absolute maximum Natings				
Supply Voltage (V _{CC})			-0.3V to +6V	
CMOS/TTL Input Voltage	-0.3V to (V _{CC} + 0.3V)			
CMOS/TTL Output Voltage	-0.3V to (V _{CC} + 0.3V)			
LVDS Receiver Input Voltage	-0.3V to (V _{CC} + 0.3V)			
LVDS Driver Output Voltage			-0.3V to (V _{CC} + 0.3V)	
LVDS Output Short Circuit Duration			Continuous	
Junction Temperature			+150°C	
Storage Temperature		−65°C to +150°C		
Lead Temperature (Soldering, 4 sec)			+260°C	
Maximum Package Power Dissipation @ +25°C	DGG0048A (TSSOP)	DS90CF563	1.98W	
	Package:	DS90CF564	1.89W	
	Package Derating:	DS90CF563	16 mW/°C above +25°C	
		DS90CF564	15 mW/°C above +25°C	

- If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
- "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be verified. They are not meant to imply that the device should be operated at these limits. The "Electrical Characteristics" specify conditions for device operation. ESD Rating: HBM (1.5 k Ω , 100 pF) PLL V CC \geq 1000V All other pins \geq 2000V EIAJ (0 Ω , 200 pF) \geq 150V

Recommended Operating Conditions

	Min	Nom	Max	Units
Supply Voltage (V _{CC})	4.75	5.0	5.25	V
Operating Free Air Temperature (T _A)	-10	+25	+70	°C
Receiver Input Range	0		2.4	V
Supply Noise Voltage (V _{CC})			100	mV_{P-P}

Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions			Тур	Max	Units					
CMOS/TTL DC SPECIFICATIONS												
V _{IH}	High Level Input Voltage			2.0		V_{CC}	V					
V _{IL}	Low Level Input Voltage			GND		8.0	V					
V _{OH}	High Level Output Voltage	I _{OH} = −0.4 mA		3.8	4.9		V					
V_{OL}	Low Level Output Voltage	I _{OL} = 2 mA			0.1	0.3	V					

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Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Units
V_{CL}	Input Clamp Voltage	$I_{CL} = -18 \text{ mA}$			-0.7 9	-1.5	V
I _{IN}	Input Current	V _{IN} = V _{CC} , GND, 2.5V or 0.4V	•		±5.1	±10	μA
los	Output Short Circuit Current	V _{OUT} = 0V				-120	mA
LVDS DR	IVER DC SPECIFICATIONS						
V _{OD}	Differential Output Voltage	R _L = 100Ω		250	290	450	mV
ΔV_{OD}	Change in V _{OD} between Complementary Output States					35	mV
V_{CM}	Common Mode Voltage			1.1	1.25	1.37 5	V
ΔV_{CM}	Change in V _{CM} between Complementary Output States					35	mV
V _{OH}	High Level Output Voltage				1.3	1.6	V
V _{OL}	Low Level Output Voltage			0.9	1.01		V
los	Output Short Circuit Current	$V_{OUT} = 0V$, $R_L = 100\Omega$			-2.9	- 5	mA
l _{OZ}	Output TRI-STATE Current	Power Down = 0V, V _{OUT} = 0V or V _{CC}	;		±1	±10	μΑ
LVDS RE	CEIVER DC SPECIFICATIONS				Į.		
V_{TH}	Differential Input High Threshold	V _{CM} = +1.2V				+100	mV
V_{TL}	Differential Input Low Threshold			-100			mV
I _{IN}	Input Current	V _{IN} = +2.4V	V _{CC} = 5.5V			±10	μA
		V _{IN} = 0V				±10	μA
TRANSMI	TTER SUPPLY CURRENT		<u>'</u>		ļ.		-
I _{CCTW}	Transmitter Supply Current,	$R_L = 100\Omega, C_L = 5 pF,$	f = 32.5 MHz		49	63	mA
	Worst Case	Worst Case Pattern (Figure 3, Figure 5)	f = 37.5 MHz		51	64	mA
		(Figure 3, Figure 3)	f = 65 MHz		70	84	mA
I _{CCTG}	Transmitter Supply Current,	$R_L = 100\Omega, C_L = 5 pF,$	f = 32.5 MHz		40	55	mA
	16 Grayscale	16 Grayscale Pattern (Figure 4, Figure 5)	f = 37.5 MHz		41	55	mA
		(Figure 4, Figure 3)	f = 65 MHz		55	67	mA
I _{CCTZ}	Transmitter Supply Current, Power Down	Power Down = Low			1	25	μΑ
RECEIVE	R SUPPLY CURRENT						
I _{CCRW}	Receiver Supply Current,	C _L = 8 pF,	f = 32.5 MHz		64	77	mA
	Worst Case	Worst Case Pattern	f = 37.5 MHz		70	85	mA
		(Figure 3, Figure 6)	f = 65 MHz		110	140	mA
I _{CCRG}	Receiver Supply Current,	C _L = 8 pF,	f = 32.5 MHz		35	55	mA
	16 Grayscale	16 Grayscale Pattern	f = 37.5 MHz		37	55	mA
		(Figure 4, Figure 6)	f = 65 MHz		55	67	mA
I _{CCRZ}	Receiver Supply Current,	Power Down = Low	1		1	10	μΑ
	Power Down						

Transmitter Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Тур	Max	Units
LLHT	LVDS Low-to-High Transition Time (Figure 5)		0.75	1.5	ns
LHLT	LVDS High-to-Low Transition Time (Figure 5)		0.75	1.5	ns
TCIT	TxCLK IN Transition Time (Figure 7)			8	ns
TCCS	TxOUT Channel-to-Channel Skew (1) (Figure 8)			350	ps

⁽¹⁾ This limit based on bench characterization.



Transmitter Switching Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter		Min	Тур	Max	Units
TCCD	TxCLK IN to TxCLK OUT Delay @ 25°C, V _{CC} = 5.0V	3.5		8.5	ns	
	(Figure 11)					
TCIP	TxCLK IN Period (Figure 9)		15	Т	50	ns
TCIH	TxCLK IN High Time (Figure 9)		0.35T	0.5T	0.65T	ns
TCIL	TxCLK IN Low Time (Figure 9)		0.35T	0.5T	0.65T	ns
TSTC	TxIN Setup to TxCLK IN (Figure 9)	f = 65 MHz	5	3.5		ns
THTC	TxIN Hold to TxCLK IN (Figure 9)		2.5	1.5		ns
TPDD	Transmitter Powerdown Delay (Figure 20)				100	ns
TPLLS	Transmitter Phase Lock Loop Set (Figure 13)				10	ms
TPPos0	Transmitter Output Pulse Position 0 (Figure 15)		-0.30	0	0.30	ns
TPPos1	Transmitter Output Pulse Position 1		1.70	1/7 T _{clk}	2.50	ns
TPPos2	Transmitter Output Pulse Position 2		3.60	$2/7 T_{clk}$	4.50	ns
TPPos3	Transmitter Output Pulse Position 3		5.90	3/7 T _{clk}	6.75	ns
TPPos4	Transmitter Output Pulse Position 4		8.30	4/7 T _{clk}	9.00	ns
TPPos5	Transmitter Output Pulse Position 5		10.40	5/7 T _{clk}	11.10	ns
TPPos6	Transmitter Output Pulse Position 6		12.70	6/7 T _{clk}	13.40	ns

Receiver Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Min	Тур	Max	Units	
CLHT	CMOS/TTL Low-to-High Transition Time (Figure 6)		2.5	4.0	ns	
CHLT	CMOS/TTL High-to-Low Transition Time (Figure 6)			2.0	3.5	ns
RCOP	RxCLK OUT Period		15	Т	50	ns
RCOH	RxCLK OUT High Time	f = 65 MHz	7.8	9		ns
RCOL	RxCLK OUT Low Time	f = 65 MHz	3.8	5		ns
RSRC	RxOUT Setup to RxCLK OUT	f = 65 MHz	2.5	4.2		ns
RHRC	RxOUT Hold to RxCLK OUT	f = 65 MHz	4.0	5.2		ns
RCCD	RxCLK IN to RxCLK OUT Delay @ 25°C, V _{CC} = 5.0V	6.4		10.7	ns	
	(Figure 12)					
RPLLS	Receiver Phase Lock Loop Set (Figure 14)	•			10	ms
RSKM	RxIN Skew Margin ⁽¹⁾ (Figure 16)	V _{CC} = 5V, T _A =25°C	600			ps
RPDD	Receiver Powerdown (Figure 19)	·			1	μs

⁽¹⁾ Receiver Skew Margin is defined as the valid data sampling region at the receiver inputs. This margin takes into account transmitter output skew (TCCS) and the setup and hold time (internal data sampling window), allowing for LVDS cable skew dependent on type/length and source clock (TxCLK IN) jitter.

RSKM ≥ cable skew (the, length) + source clock jitter (cycle to cycle)

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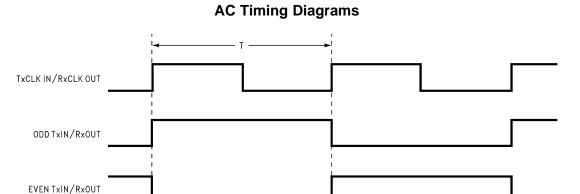
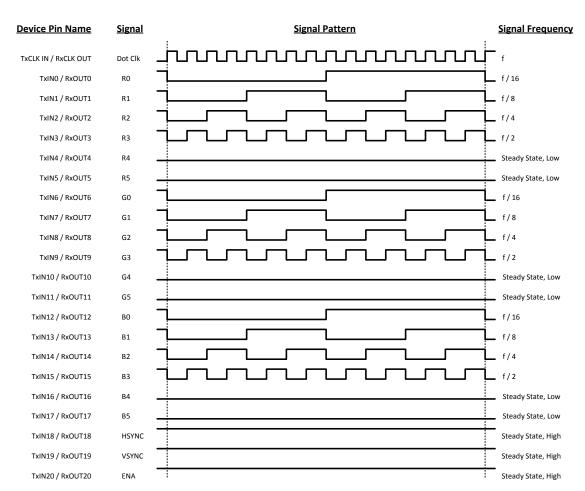


Figure 3. "Worst Case" Test Pattern



- (1) The worst case test pattern produces a maximum toggling of digital circuits, LVDS I/O and CMOS/TTL I/O.
- (2) The 16 grayscale test pattern tests device power consumption for a "typical" LCD display pattern. The test pattern approximates signal switching needed to produce groups of 16 vertical stripes across the display.
- (3) Figure 3 and Figure 4 show a falling edge data strobe (TxCLK IN/RxCLK OUT).
- (4) Recommended pin to signal mapping. Customer may choose to define differently.

Figure 4. "16 Grayscale" Test Pattern



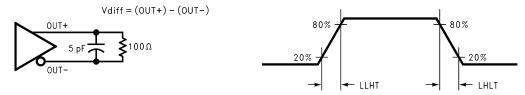


Figure 5. DS90CF563 (Transmitter) LVDS Output Load and Transition Times

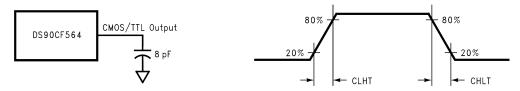


Figure 6. DS90CF564 (Receiver) CMOS/TTL Output Load and Transition Times

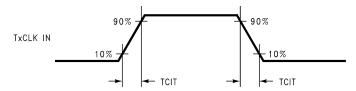
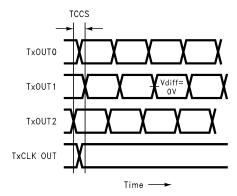


Figure 7. DS90CF563 (Transmitter) Input Clock Transition Time



Note: Measurements at Vdiff = 0V

Note: TCSS measured between earliest and latest LVDS edges.

Note: TxCLK Differential High→Low Edge

Figure 8. DS90CF563 (Transmitter) Channel-to-Channel Skew and Pulse Width

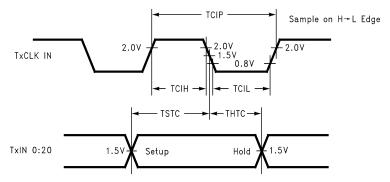


Figure 9. DS90CF563 (Transmitter) Setup/Hold and High/Low Times



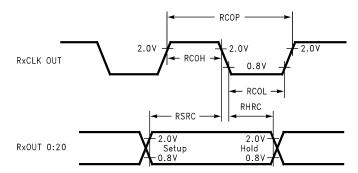


Figure 10. DS90CF564 (Receiver) Clock In to Clock Out Delay

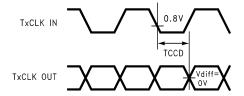


Figure 11. DS90CF563 (Transmitter) Clock In to Clock Out Delay

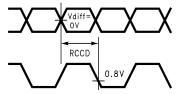


Figure 12. DS90CF564 (Receiver) Clock In to Clock Out Delay

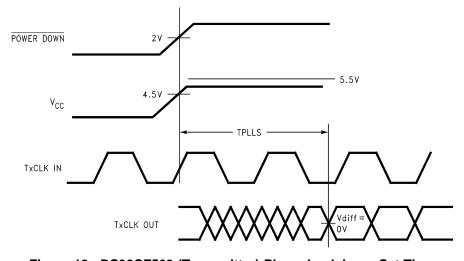


Figure 13. DS90CF563 (Transmitter) Phase Lock Loop Set Time



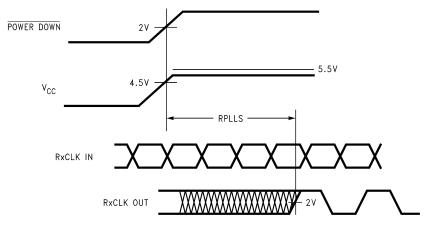


Figure 14. DS90CF564 (Receiver) Phase Lock Loop Set Time

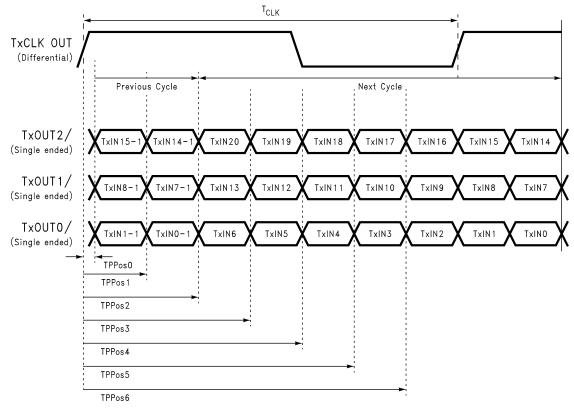
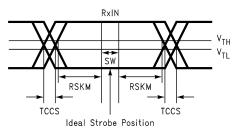


Figure 15. Transmitter LVDS Output Pulse Position Measurement





SW-Setup and Hold Time (Internal Data Sampling Window)

TCCS—Transmitter Output Skew

RSKM ≥ Cable Skew (type, length) + Source Clock Jitter (cycle to cycle)

Cable Skew—typically 10 ps-40 ps per foot

Figure 16. Receiver LVDS Input Skew Margin

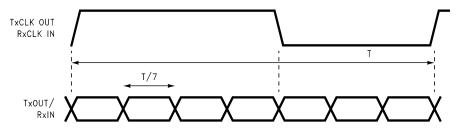


Figure 17. Seven Bits of LVDS in One Clock Cycle

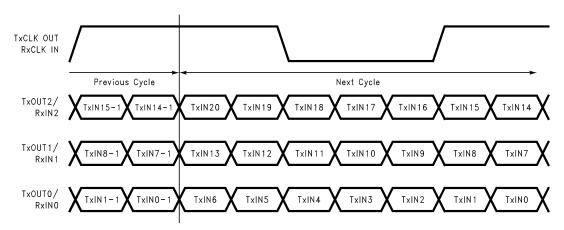


Figure 18. 21 Parallel TTL Data Inputs Mapped to LVDS Outputs (DS90CF563)

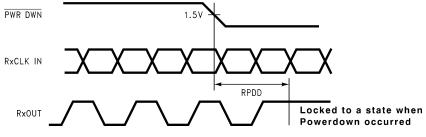


Figure 19. Receiver Powerdown Delay



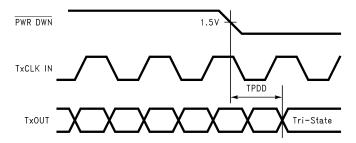


Figure 20. Transmitter Powerdown Delay

DS90CF563 Pin Descriptions—FPD Link Transmitter

Pin Name	I/O	No.	Description
TxIN	-	21	TTL level input. This includes: 6 Red, 6 Green, 6 Blue, and 3 control lines—FPLINE, FPFRAME, DRDY (also referred to as HSYNC, VSYNC, Data Enable)
TxOUT+	0	3	Positive LVDS differential data output
TxOUT-	0	3	Negative LVDS differential data output
FPSHIFT IN	I	1	TTL level clock input. The falling edge acts as data strobe
TxCLK OUT+	0	1	Positive LVDS differential clock output
TxCLK OUT-	0	1	Negative LVDS differential clock output
PWR DOWN	I	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at power down
V _{CC}	ı	4	Power supply pins for TTL inputs
GND	I	5	Ground pins for TTL inputs
PLL V _{CC}	I	1	Power supply pin for PLL
PLL GND	I	2	Ground pins for PLL
LVDS V _{CC}	I	1	Power supply pin for LVDS outputs
LVDS GND	I	3	Ground pins for LVDS outputs

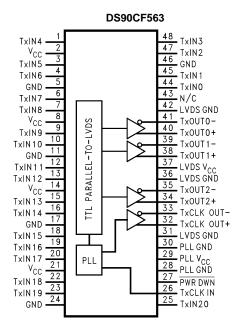
DS90CF564 Pin Descriptions—FPD Link Receiver

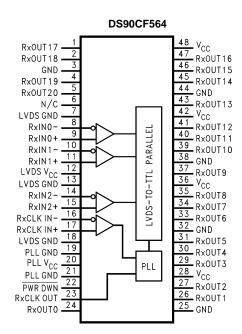
Pin Name	I/O	No.	Description					
RxIN+	ı	3	Positive LVDS differential data inputs					
RxIN-	I	3	Negative LVDS differential data inputs					
RxOUT	0	21	vel data outputs. This includes: 6 Red, 6 Green, 6 Blue, and 3 control lines—FPLINE, FPFRAME, (also referred to as HSYNC, VSYNC, Data Enable)					
RxCLK IN+	ı	1	Positive LVDS differential clock input					
RxCLK IN-	ı	1	ative LVDS differential clock input					
FPSHIFT OUT	0	1	level clock output. The falling edge acts as data strobe					
PWR DOWN	ı	1	TTL level input. Assertion (low input) maintains the receiver outputs in the previous state					
V _{CC}	ı	4	Power supply pins for TTL outputs					
GND	I	5	Ground pins for TTL outputs					
PLL V _{CC}	I	1	Power supply for PLL					
PLL GND	I	2	Ground pin for PLL					
LVDS V _{CC}	I	1	Power supply pin for LVDS inputs					
LVDS GND	I	3	Ground pins for LVDS inputs					

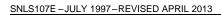
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Connection Diagram









REVISION HISTORY

Ch	anges from Revision D (April 2013) to Revision E	Pa	ge
•	Changed layout of National Data Sheet to TI format		11



PACKAGE OPTION ADDENDUM

17-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
DS90CF564MTD/NOPB	ACTIVE	TSSOP	DGG	48	38	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-10 to 70	DS90CF564MTD >B	Samples
DS90CF564MTDX/NOPB	ACTIVE	TSSOP	DGG	48	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-10 to 70	DS90CF564MTD >B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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